Trench-based Schottky Rectifier, Exceptionally Low Leakage

NRVTS560ETFS, NRVTS560ETFSWF

Features

- Fine Lithography Trench-based Schottky Technology for Very Low Leakage
- Fast Switching with Exceptional Temperature Stability
- Low Power Loss and Lower Operating Temperature
- Higher Efficiency for Achieving Regulatory Compliance
- Low Thermal Resistance
- High Surge Capability
- NRV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- Wettable Flanks (WF in PM Suffix) Option Available for Enhanced Automated Optical Inspection (AoI)
- These are Pb-Free and Halide-Free Devices

Typical Applications

- Switching Power Supplies including Wireless, Smartphone and Notebook Adapters
- High Frequency and DC-DC Converters
- Freewheeling and OR-ing diodes
- Reverse Battery Protection
- Instrumentation
- Automotive LED Lighting

Mechanical Characteristics:

- Case: Epoxy, Molded
- Epoxy Meets Flammability Rating UL 94-0 @ 0.125 in.
- Lead Finish: 100% Matte Sn (Tin)
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Device Meets MSL 1 Requirements
- Mass Approximately 25 mg



ON Semiconductor®

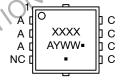
www.onsemi.com

SCHOTTKY BARRIER RECTIFIERS 5 AMPERES 60 VOLTS



MARKING DIAGRAM





XXXX = Specific Device Code A = Assembly Location

Y = Year
WW = Work Week
= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 4 of this data sheet.

NRVTS560ETFS, NRVTS560ETFSWF

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	60	V
Average Rectified Forward Current (Rated V _R , T _C = 168°C)	I _{F(AV)}	5.0	A
Peak Repetitive Forward Current, (Rated V_R , Square Wave, 20 kHz, T_C = 167°C)	I _{FRM}	10	Α
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I _{FSM}	120	Α
Storage Temperature Range	T _{stg}	−65 to +175	°C
Operating Junction Temperature		−55 to +175	°C
Unclamped Inductive Switching Energy (10 mH Inductor, Non-repetitive)		50	mJ
ESD Rating (Human Body Model)		3A	7
ESD Rating (Machine Model)		M4 S	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

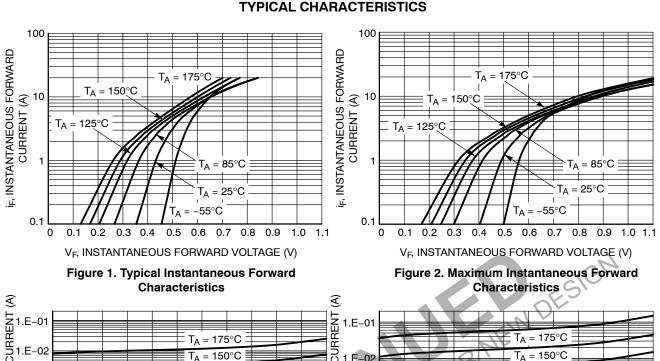
Characteristic		Symbol	Max	Unit
Thermal Resistance, Junction-to-Case, Steady State (Assumes 600 mm² 1 oz. copper bond pad, on a FR4 board)		R _{eJC}	2.6	°C/W

ELECTRICAL CHARACTERISTICS

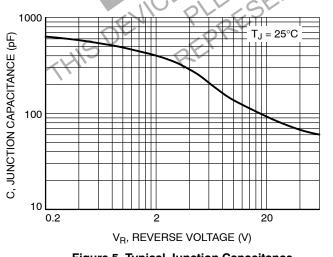
Characteristic	Symbol	Тур	Max	Unit
Instantaneous Forward Voltage (Note 1)	V _F			V
(i _F = 2.5 Amps, T _J = 25°C)	_	0.48	_	
(i _F = 5.0 Amps, T _J = 25°C)		0.54	0.68	
(i _F = 2.5 Amps, T _J = 125°C)		0.40	_	
(i _F = 5.0 Amps, T _J = 125°C)		0.50	0.65	
Instantaneous Reverse Current (Note 1)	i _R			
(Rated dc Voltage, $T_J = 25^{\circ}C$)		_	50	μΑ
(Rated dc Voltage, T _J = 125°C)		2.2	5	mA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 1. Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.

NRVTS560ETFS, NRVTS560ETFSWF



(E) 1.E-01 1.E-02 1.E-03 1.E-04 1.E-05 1.E-05 1.E-07 INSTANTANEOUS REVERSE CURRENT (A) 1.E-03 1.E-03 1.E-04 1.E-05 1.E-05 T_A = 125°C $T_A = 125^{\circ}C$ $T_A = 85^{\circ}C$ $T_A = 25^{\circ}C$ $T_A = 25^{\circ}C$ 55 60 25 30 35 40 25 30 35 40 45 V_R, INSTANTANEOUS REVERSE VOLTAGE (V) V_R, INSTANTANEOUS REVERSE VOLTAGE (V) Figure 3. Typical Reverse Characteristics



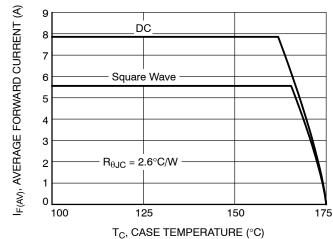


Figure 4. Maximum Reverse Characteristics

Figure 5. Typical Junction Capacitance Figure 6. Current Derating per Device

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TYPICAL CHARACTERISTICS

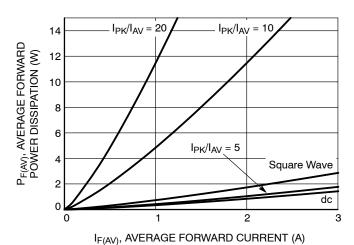


Figure 7. Forward Power Dissipation

SIGN 100 50% Duty Cycle 20% 10 10% R_{BJA}(t) (°C/W) Assumes 25°C ambient and soldered to a 650 mm² - 1 oz copper pad on PCB Single Pulse 0.01 0.000001 0.001 0.0001 10 100 1000 0.00001 PULSE TIME (sec)

Figure 8. Typical Thermal Response, Junction-to-Ambient

DEVICE ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
NRVTS560ETFSTAG	T560	μ8FL (Pb-Free)	1500 / Tape & Reel
NRVTS560ETFSWFTAG	T56W	μ8FL (Pb-Free)	1500 / Tape & Reel
NRVTS560ETFSTWG	T560	μ8FL (Pb–Free)	5000 / Tape & Reel
NRVTS560ETFSWFTWG	T56W	μ8FL (Pb–Free)	5000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



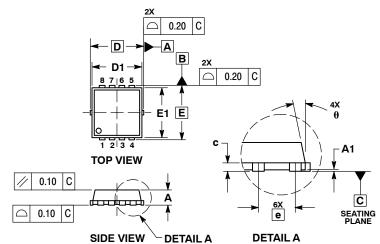




SCALE 2:1

WDFN8 3.3x3.3, 0.65P CASE 511AB ISSUE D

DATE 23 APR 2012



NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
 DIMENSION D1 AND E1 DO NOT INCLUDE MOLD FLASH
 PROTRUSIONS OR GATE BURRS.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.70	0.75	0.80	0.028	0.030	0.031
A1	0.00		0.05	0.000		0.002
b	0.23	0.30	0.40	0.009	0.012	0.016
С	0.15	0.20	0.25	0.006	0.008	0.010
D	3.30 BSC			0	.130 BSC	
D1	2.95	3.05	3.15	0.116	0.120	0.124
D2	1.98	2.11	2.24	0.078	0.083	0.088
E	3.30 BSC		0.130 BSC			
E1	2.95	3.05	3.15	0.116	0.120	0.124
E2	1.47	1.60	1.73	0.058	0.063	0.068
E3	0.23	0.30	0.40	0.009	0.012	0.016
е	0.65 BSC		0.026 BSC			
G	0.30	0.41	0.51	0.012	0.016	0.020
K	0.65	0.80	0.95	0.026	0.032	0.037
L	0.30	0.43	0.56	0.012	0.017	0.022
L1	0.06	0.13	0.20	0.002	0.005	0.008
М	1.40	1.50	1.60	0.055	0.059	0.063
θ	0 °		12 °	0 °		12 °

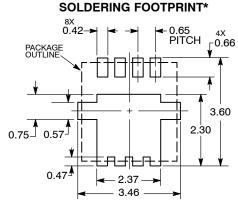


GENERIC MARKING DIAGRAM*



XXXXX = Specific Device Code Α = Assembly Location

= Year = Work Week WW = Pb-Free Package



DIMENSION: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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DESCRIPTION:	WDFN8 3.3X3.3, 0.65P		PAGE 1 OF 1	

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^{*}This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

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onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at

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